



*Muons, Inc.*

# Simulation of Conventional and Unconventional Photo- cathode Geometries

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20 July 2009

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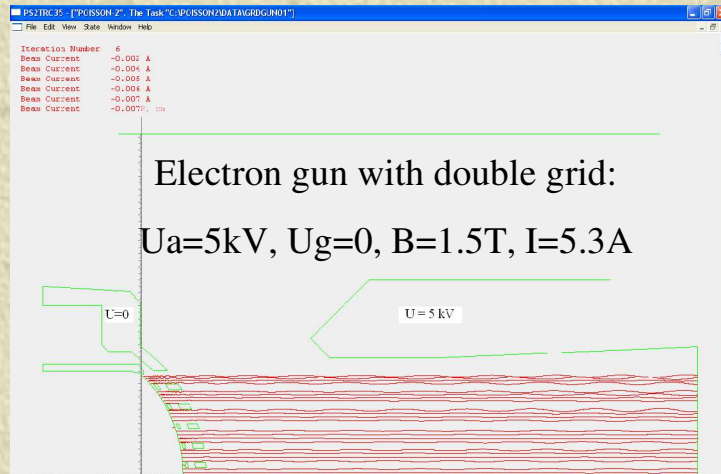
1<sup>st</sup> Workshop on Photo-cathodes

# Outline

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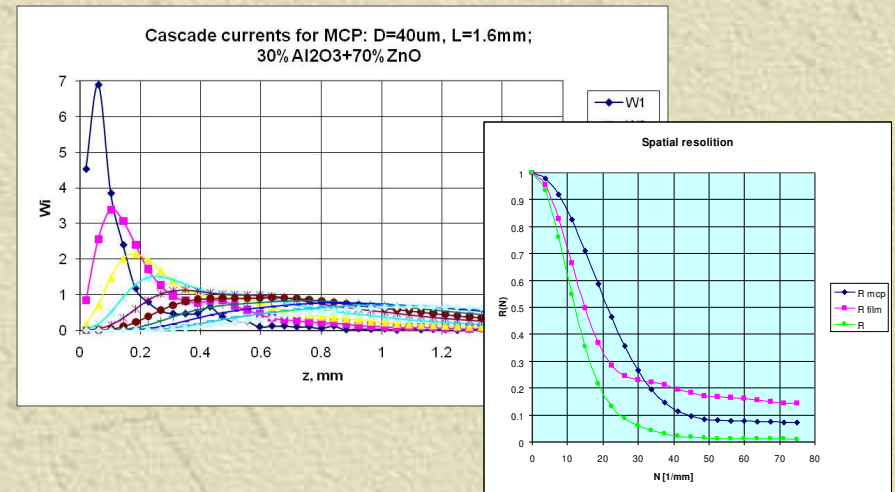
- ✦ Brief review of numerical toolkit for micro channel plate simulation;
- ✦ Optimization of the photo electron capturing for Funnel MCP;
- ✦ Conventional MCPs with composite secondary emitters;
- ✦ Comparison of emission properties for different analytic models;
- ✦ Future problems;
- ✦ Resume.

# Original software toolkit to simulate the MCPs



General purpose 2D electron  
optical relativistic code

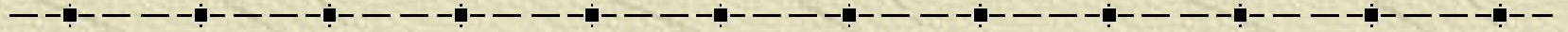
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Micro channel plate simulator MCPS



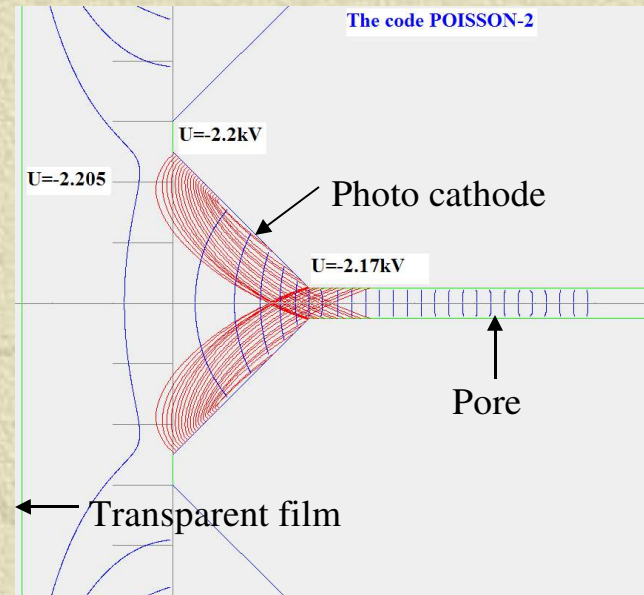
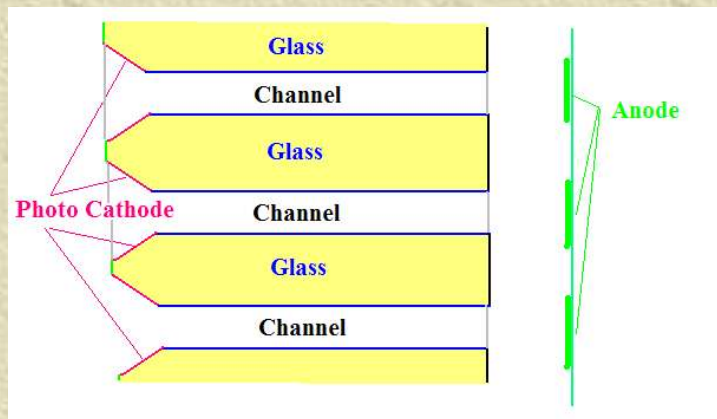
Monte Carlo simulator MCS



# Part 1.

## Funnel MCP

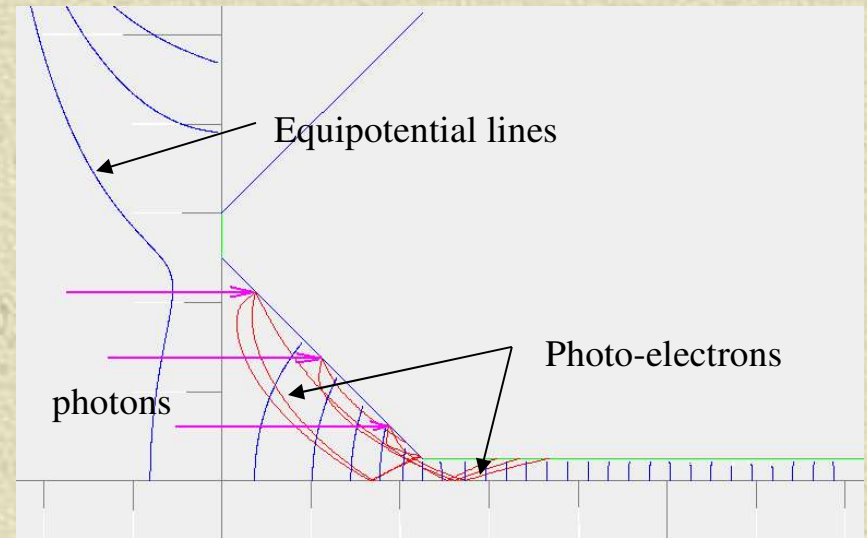
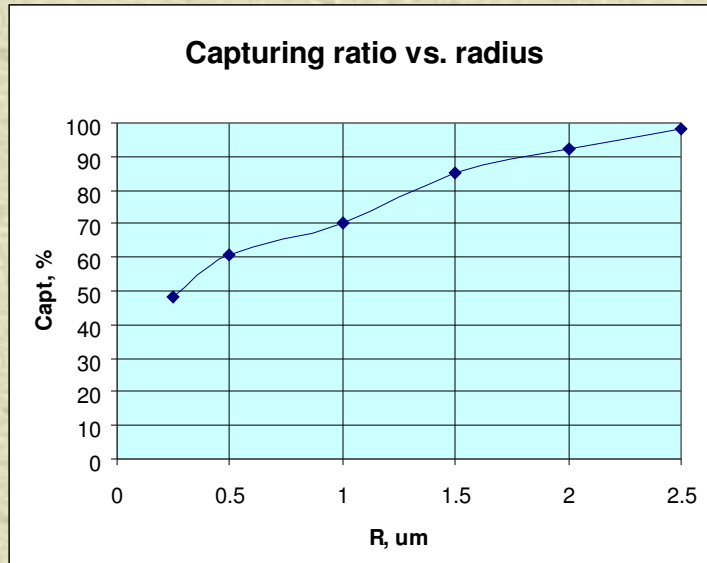
# Funnel type MCP (FMCP)



FMCP is an alternative version of conventional MCP which can prevent the ion feedback damage. FMCP also makes easier the first-strike problem.

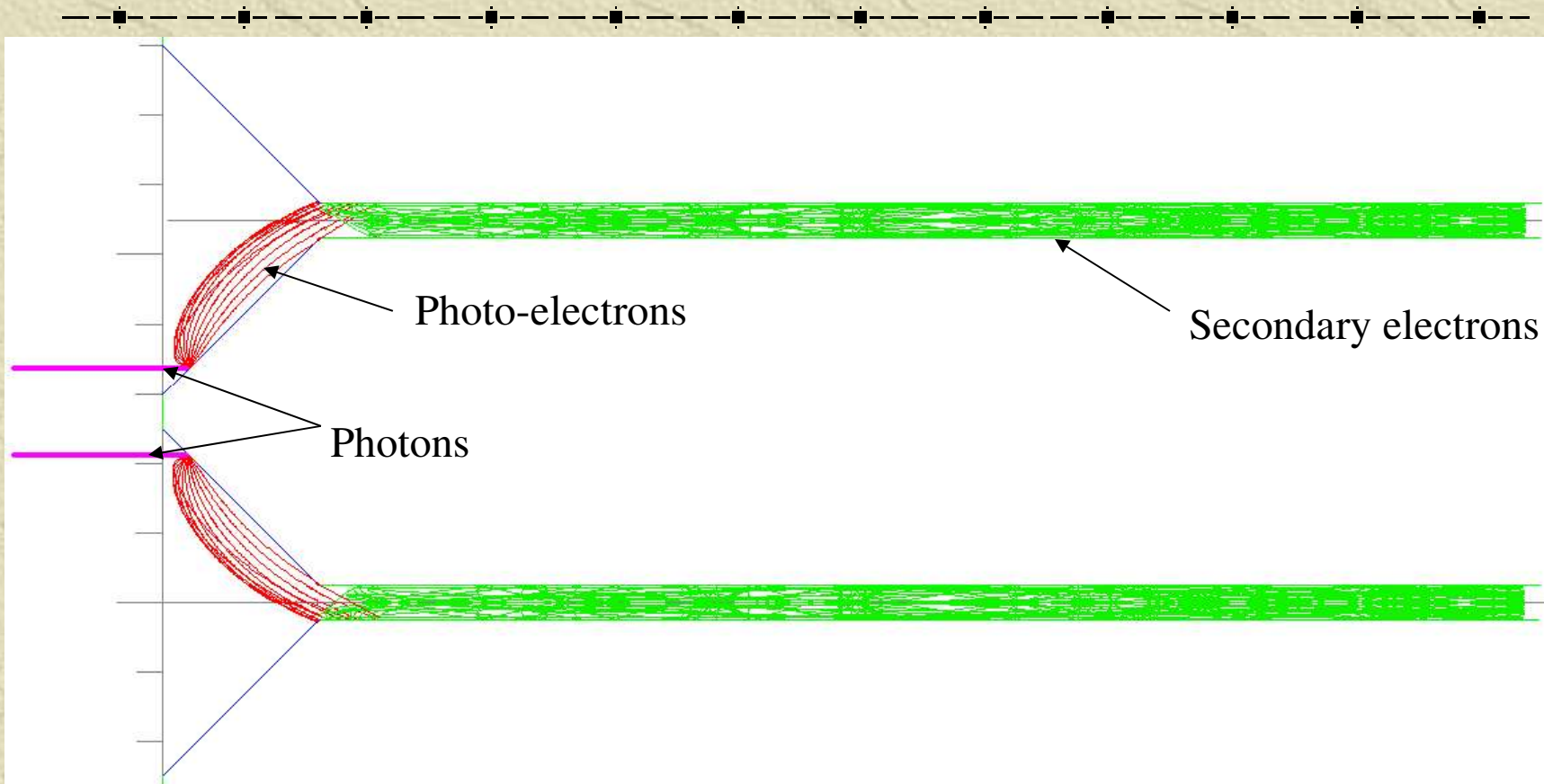
Optimization of capturing ratio for photo-electrons by varying the outer radius and resistance of photo cathode

# Efficiency of photo emission



The efficiency of photo-electron capturing depends on many factors (funnel geometry, photo-cathode resistance, voltage etc.). It is strongly depends on the position at the cathode surface

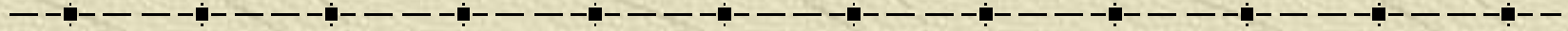
# Electron multiplication in the funnel MCP



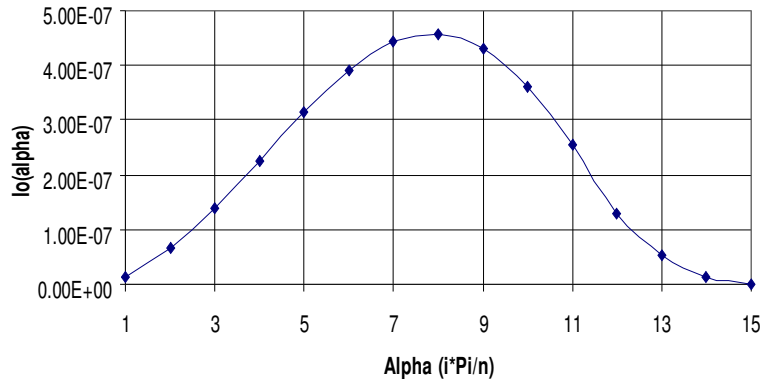
The result of numerical simulation for the electron multiplication in 5 $\mu$ m pores.

Parameters:  $L/D=40$ ; Material properties:  $\Sigma_{max}=3$ ;  $U_{max}=400V$ .

# Numerical results for FMCP simulation

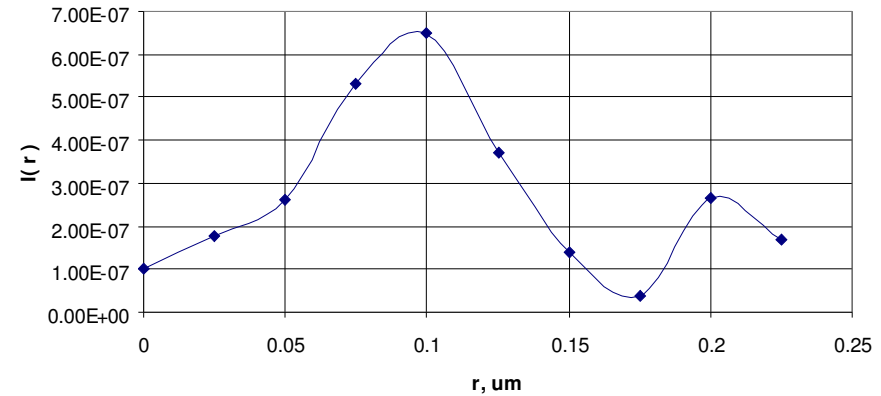


Angular distribution of photo emission



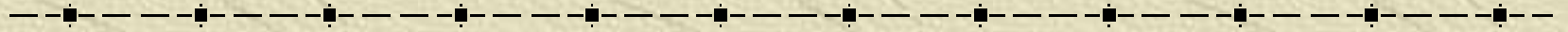
Angular distribution of photo emission is described by  $\text{Cos}(\text{Theta})$  dependence

Current distribution at the end of pore



Current distribution of secondary electrons at cross-section  $Z=20\mu\text{m}$

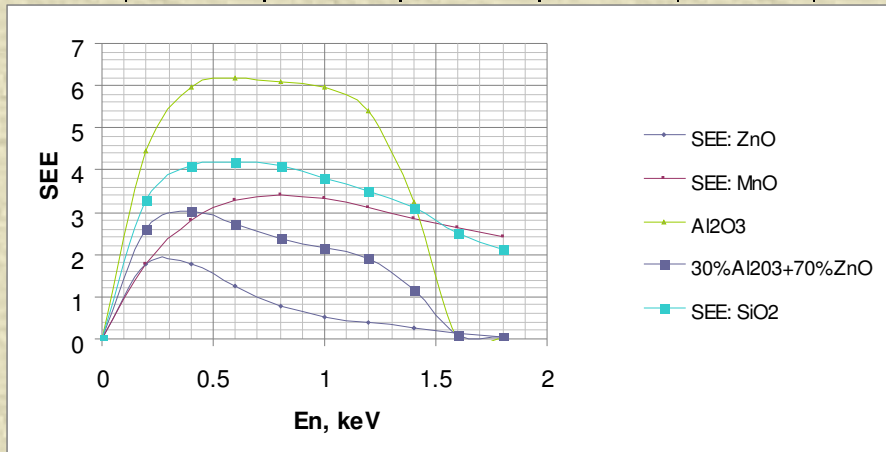




## Part 2.

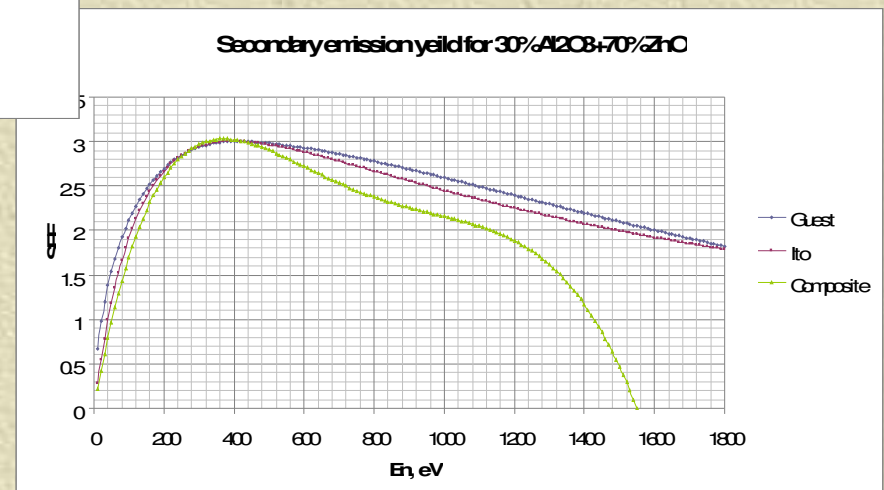
# Conventional MCP

# Secondary emission for composite materials



Secondary emission properties for different materials common used as the emitters in MCP

The approximations of SEE curve for composite material (30%Al<sub>2</sub>O<sub>3</sub>+70%ZnO) used in different semi-analytical models



These approximations were used in simulation of the INCOM MCP with parameters:  $D=40\mu\text{m}$ ,  $L/D=40$ ,  $L=1.6\text{mm}$ , Voltage  $U=1\text{kV}$

# Comparison for different Secondary-emission models

## 1. Guest's Model

$$\sigma(\theta, V) = \left( \frac{V}{V_{max}} \sqrt{\cos(\theta)} \right)^\beta \exp \left[ \alpha (1 - \cos(\theta)) + \beta \left( 1 - \frac{V}{V_{max}} \sqrt{\cos(\theta)} \right) \right],$$

$$\begin{aligned} 0.55, V \leq V_{max}, \\ 0.25, V > V_{max}, \\ \beta = \frac{z}{z_0} \end{aligned}$$

$\theta$  – incident angle,  $V$  – impact energy,  
 $V_{max}$  – impact energy corresponds to a maximum of SEE yield,  
 $\alpha$  – surface absorption factor,  $\beta$  – smooth factor

## 3. Lie-Dekker Model

$$\sigma_{max}(\theta) = \sigma_{max}(0) \left( 1 + \frac{k\theta^2}{\pi} \right), V_{max}(\theta) = V_{max}(0) \left( 1 + \frac{k\theta^2}{\pi} \right),$$

$$\sigma = \sigma_{max} g_n(z_m V / V_{max}) / g_n(z_m),$$

$$g_n(z) = \frac{1 - \exp(-z^{n+1})}{z^n},$$

$k=0$  for textured carbon, 1.5 for polished surface, 2 for crystalline (1 – default);

$z_m$  – is an argument value corresponds to the maximum of  $g_n(z)$ ,

$n$  – is an adjustable parameter (default value is 0.35 for  $V \leq V_{max}$ ,

$z_m=1.84$ ,  $g_n(z_m)=0.725$ , and 1 for  $V > 3 V_{max}$ );

## 2. Ito's Model

$$\sigma(\theta, V) = \frac{4x}{(x+1)^2} \exp[\beta(1 - \cos \theta)]$$

$$x = \frac{V}{V_{max}} \sqrt{\cos \theta},$$

## 4. Agarwal's Model

$$\sigma = \sigma_{max} \frac{2V/V_{max}}{1 + (V/V_{max})^{1.85} (\frac{2Z}{A})}$$

$Z$  is atomic number and  $A$  the atomic weight

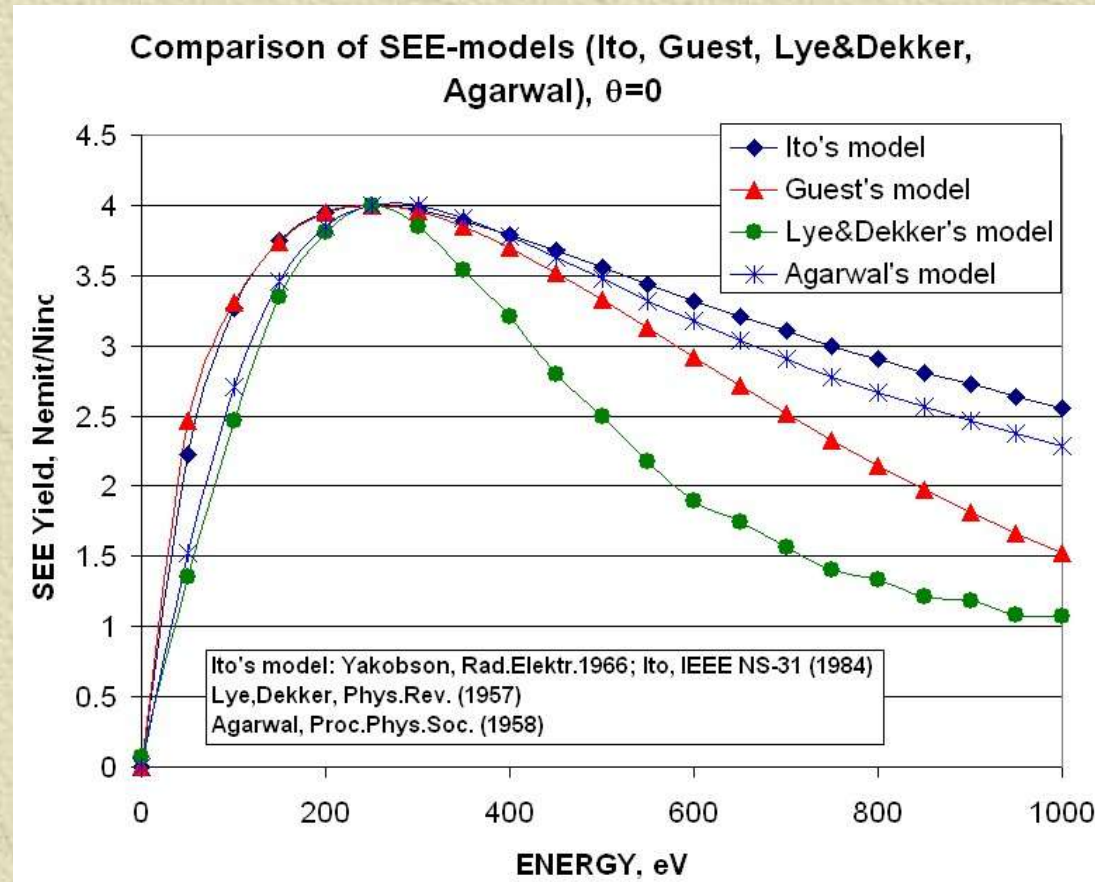
## 5. Rodney-Vaughan's Model

$$\sigma = \sigma_{max} (v e^{1-v})^s, v = \frac{V - V_0}{V_{max} - V_0},$$

$s=0.62$  for  $v < 1$ , and  $s=0.25$  for  $v > 1$ .

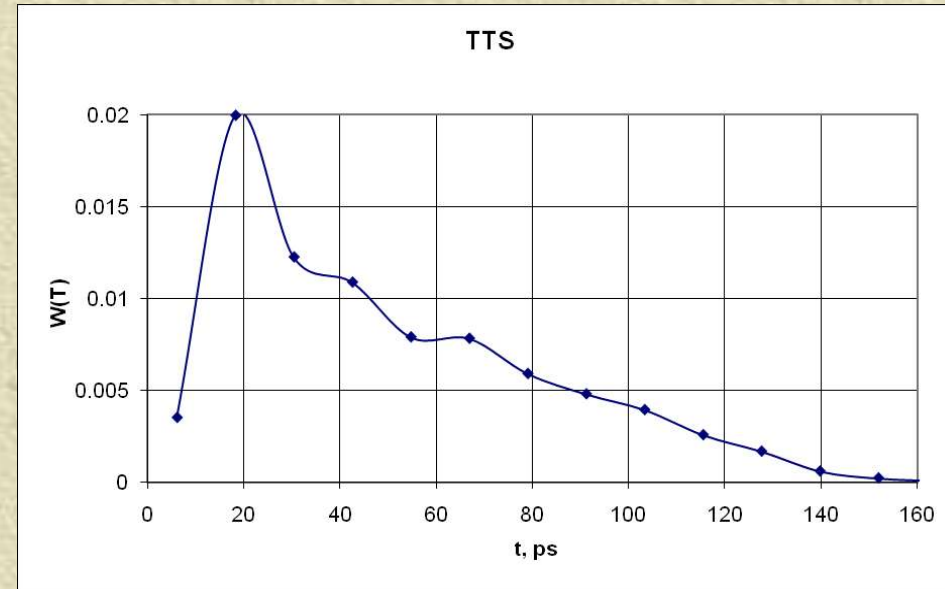
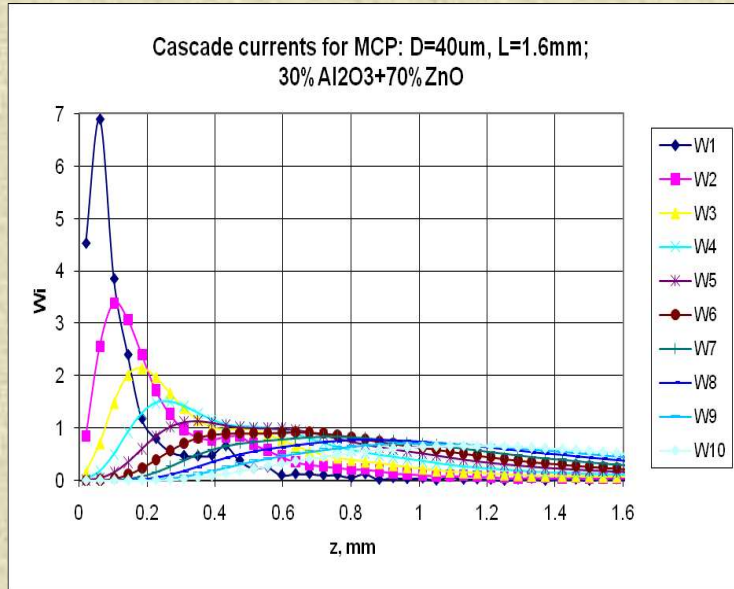
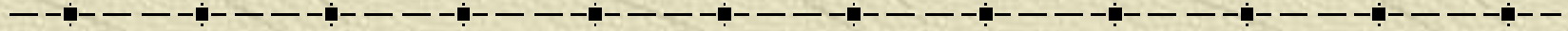
$V_0$  is biggest value for SEE curve  $\sigma(V_0)=1$

# Comparison for different models (cont.)



Courtesy of Z.Insepov

# The results of INCOM MCP simulation



MCP parameters: D=40um, L/D=40, L=1.6mm, Voltage U=1kV.

Time resolution for the MCP  $R_t=33.1$  ps. Actual resolution with PC-MCP and MCP-anode gaps will be bigger. Different emission models give difference in the gain computation about 30-40%.

# Nearest future plans

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- ✦ Extend the field representation in the pores to take into account the tilted electric field in chevron-pair plates which can substantially increase the gain;
- ✦ Incorporate the saturation model to our numerical codes;
- ✦ Provide systematic comparison for emission models with experimental data.

# Resume

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- ✦ Numerical optimization of funnel MCP parameters substantially increased the capturing of photo-electrons and total gain factor;
- ✦ Simulation of conventional MCP with secondary emitter of composite material detects a big difference in the gain factor for different analytical models;
- ✦ Existing numerical codes should be improved to satisfy the main requirements in simulation of modern MCP photo-detectors.